# 2SD2528

### Silicon NPN epitaxial planar type

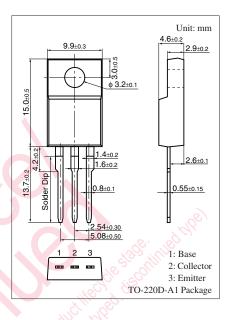
For power amplification and high-current amplification

#### Features

- High forward current transfer ratio  $h_{FE}$
- $\bullet$  Satisfactory linearity of forward current transfer ratio  $h_{\rm FE}$
- Full-pack package which can be installed to the heat sink with one screw

Absolute Maximum Hatings $T_a = 25$ C							
Parameter	Symbol	Rating	Unit				
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	80	V				
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	60	V				
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	6	V				
Collector current	I <sub>C</sub>	5	Α				
Peak collector current	I <sub>CP</sub>	10	A				
Base current	I <sub>B</sub>	1	A				
Collector power $T_C = 25^{\circ}C$	P <sub>C</sub>	40	W				
dissipation		2.0					
Junction temperature	Tj	150	°C				
Storage temperature	T <sub>stg</sub>	-55 to +150	°C				





#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

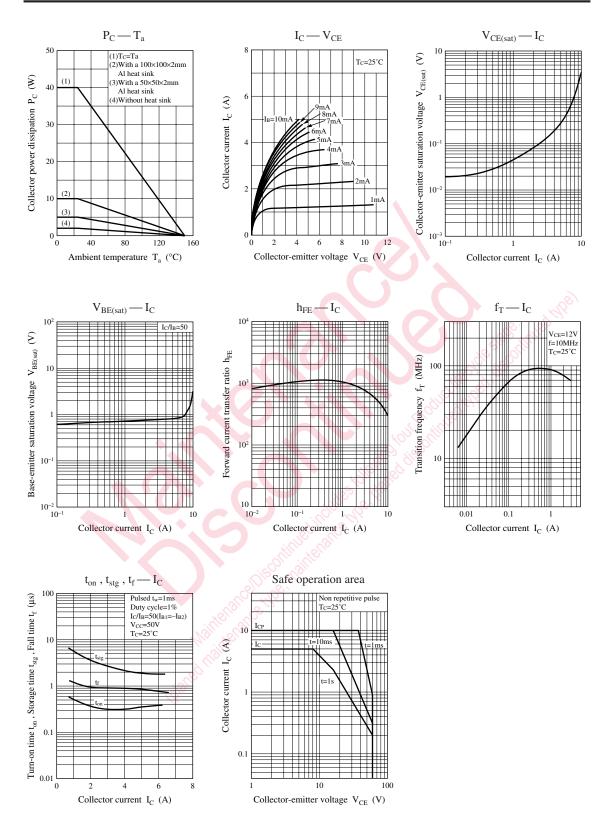
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_{\rm C} = 25 \text{ mA}, I_{\rm B} = 0$	60			V
Collector-base cutoff current (Emitter open)	I <sub>CBO</sub>	$V_{CB} = 80 V, I_E = 0$			100	μA
Emitter-base cutoff current (Collector open)	I <sub>EBO</sub>	$V_{EB} = 6 V, I_C = 0$			100	μΑ
Forward current transfer ratio	h <sub>FE</sub> *	$V_{CE} = 4 V, I_C = 1 A$	500		2 0 0 0	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = 4 \text{ A}, I_{\rm B} = 0.1 \text{ A}$			0.3	V
Transition frequency	fT	$V_{CE} = 12 \text{ V}, I_C = 0.4 \text{ A}, f = 10 \text{ MHz}$		30		MHz
Turn-on time	t <sub>on</sub>	$I_C = 4 A$ , $I_{B1} = 0.08 A$ , $I_{B2} = -0.08 A$		0.4		μs
Storage time	t <sub>stg</sub>	$V_{CC} = 50 V$		2.0		μs
Fall time	t <sub>f</sub>			0.6		μs

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. \*: Rank classification

Rank	Q	Р
h <sub>FE1</sub>	500 to 1 200	800 to 2000

## Panasonic



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